

Light-induced nuclear quadrupolar relaxation in semiconductors

D. Paget,^{a*} T. Amand,^b J. -P. Korb^a

^a Laboratoire de Physique de la Matière Condensée, Ecole Polytechnique CNRS, 91128 Palaiseau Cedex, France.

^b Laboratoire de Physique et Chimie des Nano-Objets, INSA-CNRS-UPS, 135 avenue de Rangueil, 31077 Toulouse Cedex 4, France.

Abstract:

Light excitation of a semiconductor, known to dynamically-polarize the nuclear spins by hyperfine contact interaction with the photoelectrons, also generates an intrinsic nuclear *depolarization* mechanism. This novel relaxation process arises from the modulation of the nuclear quadrupolar Hamiltonian by photoelectron trapping and recombination at nearby localized states. For nuclei near shallow donors, the usual diffusion radius is replaced by a smaller, quadrupolar, radius. If the light excitation conditions correspond to partial donor occupation by photoelectrons, the nuclear magnetization and the nuclear field can be decreased by more than one order of magnitude.

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* Corresponding author : daniel.paget@polytechnique.fr

I Introduction

In a semiconductor, the possibility to enhance the nuclear polarization by the hyperfine contact interaction with spin-polarized electrons generated by circularly-polarized light excitation is of interest both for fundamental reasons and, among others, for applications to :
i) quantum computing ¹ ii) transfer of nuclear magnetization to biological systems, as an alternative to adsorption of polarized xenon,^{2,3} iii) understanding of the fractional quantum Hall effect.⁴ Further potential applications of the optical increase of NMR sensitivity include extension to nuclei of *single spin* investigations using magnetic resonance force microscopy at surfaces.⁵

After the demonstration of optical nuclear polarization in silicon,⁶ a number of recent investigations of the optically-enhanced *bulk* nuclear magnetization have been undertaken using standard NMR in Si,⁷ GaAs,⁸⁻¹³ InP,¹⁴ CdTe.¹⁵ Some of the results¹¹⁻¹³ were used to verify the predictions of a general theory for nuclear relaxation in solids according to which the presence of paramagnetic impurities, or localized centers, is crucial for relaxation of the nuclear spin system.¹⁶⁻¹⁸ Nuclei close to the centers are relaxed by the hyperfine interaction with the spin-polarized photoelectrons trapped at these impurities, while the bulk nuclear spin system is relaxed by spin diffusion from the latter minority nuclei. A diffusion radius is defined corresponding to the distance from the impurity separating the two types of relaxation processes.¹⁹

Optical detection of NMR, from the depolarization at resonance of the luminescence, was first reported for GaAlAs in 1974,²⁰ and subsequently applied to several III-V semiconductors,²¹⁻²⁴ as well as 2D systems^{8,25} and quantum dots.^{26,27} For bulk materials, this technique was shown to only detect nuclei near the sites of electronic localization, which verifies the existence of a diffusion radius.²⁸ The value of the nuclear hyperfine field acting on the electrons is consistently smaller than the expected value, found from the optically measured

electronic spin polarization. The corresponding leakage factor is found equal to 0.1 for GaAs,²⁹ 0.02 in GaSb,²² and of several percent in InP.²³ Such decrease is likely to significantly reduce the optical enhancement of the nuclear polarization.

The identification of the relaxation mechanisms responsible for this loss of nuclear polarization remains an open problem. In the absence of light excitation, the hyperfine coupling with the unpolarized holes,³⁰ or the quadrupolar interaction modulated by lattice phonons³¹ are negligible at low temperature. The total hyperfine field of nuclei near shallow donors is decreased because of the competition between spin-lattice relaxation and spin diffusion, but only by a factor 3.²⁸ Interestingly, in addition to the dynamic nuclear polarization, light excitation also creates an *intrinsic leakage mechanism* for the same nuclei as the ones which are dynamically-polarized. The nuclei close to shallow donors experience a very strong electric field from the ionized donor. Since the latter field is modulated by trapping and recombination of photoelectrons, there results a significant nuclear depolarization.

The present work is devoted to an evaluation of the efficiency of such light-induced nuclear relaxation. In Sec. II, the characteristic correlation time of the quadrupolar-induced evolution of the nuclear spin temperature is calculated using the semi-classical rate equation for evolution of the nuclear spin density matrix.³² Quantitative estimates are performed in Sec. III in the particular case of nuclei near shallow donors, using the known magnitudes of quadrupolar³³⁻³⁵ and hyperfine couplings.²⁹ Provided the light power density is such that shallow donors are partially occupied, the light-induced quadrupolar relaxation is found to induce a decrease of the nuclear polarization and of the nuclear hyperfine field by as much as one order of magnitude. The corresponding effect in quantum dots and the resulting dependence of the nuclear field as a function of temperature and light excitation power will be discussed elsewhere.³⁶

II Light-induced quadrupolar nuclear relaxation time

In the absence of a trapped photoelectron, the electric field experienced by nuclei near a shallow donor is given by

$$E_{off}(r) = \frac{|e|}{4\pi\epsilon\epsilon_0} \cdot \frac{1}{r^2} \quad (1)$$

where e is the electronic charge, ϵ is the static dielectric constant and r is the distance from the donor. Photoelectron trapping and recombination induces a modulation of the electric field between Eq. (1) and $E_{on}(r)$ such that

$$E_{on}(r) = E_{off}(r) [1 - s(r)] \quad (2)$$

where the expression for $s(r)$, found using Gauss's theorem and the shape of the electronic wavefunction, is

$$s(r) = 1 - \left[1 + \frac{2r}{a_0^*} + \frac{2r^2}{a_0^{*2}} \right] e^{-2r/a_0^*} \quad (3)$$

Here a_0^* is the electronic Bohr radius. In GaAs, one has $s(a_0^*) \approx 0.3$ and $E_{off}(a_0^*)$ is of the order of 10^6 V/m. The modulation amplitude $E_{off} - E_{on}$ induced by photoelectron trapping and recombination is very large. Unlike the usual quadrupolar relaxation, the corresponding relaxation process does not rely on phonons for modulation and can be relevant at low temperature. The present section is devoted to the calculation of its efficiency in the model case of nuclei near shallow donors in semiconductors.

A Quadrupolar Hamiltonian

The nuclear spin Hamiltonian, given by $H = Z + H_{IS} + H_{SS} + H_Q$, is the sum of the Zeeman term Z , of the hyperfine Hamiltonian H_{IS} , of the nuclear spin-spin interaction H_{SS} and

of the quadrupolar interaction H_Q . The expressions for the first three terms can be found in Ref. (29). For a cubic semiconductor, the expression for the quadrupolar Hamiltonian is given in Appendix A for arbitrary magnetic field B and sample surface orientations. If the magnetic field is perpendicular to a (001) sample surface, the quadrupolar Hamiltonian is simpler:

$$H_Q = F_Q(r) \cdot \sum_{k=1}^2 [A_{Qk} + A_{Qk}^+] \quad (4)$$

The spin operators A_{Qk} are given by

$$\begin{aligned} A_{Q1} &= \sin \theta e^{i(\varphi - \pi/2)} [I_z I_+ + I_+ I_z] \\ A_{Q2} &= -i \cos \theta I_+^2 \end{aligned} \quad (5)$$

and the Hermitian conjugate operators A_{Qk}^+ are obtained by replacing i by $-i$ and therefore I_+ by I_- . Here θ is the angle between the electric field \vec{E} , lying along the Z direction and the normal z to the surface, and φ is the angle between the x direction and the zZ plane. The operators A_{Qk} induce transitions at an energy given by

$$\hbar \omega_k = k \hbar \gamma B \quad (k=1,2) \quad (6)$$

where γ is the nuclear gyromagnetic ratio. It is convenient to write^{37,38}

$$F_Q(r) = \frac{eR_{14}Q}{4I(2I-1)} E(r) = \hbar \gamma b_Q E(r) \quad (7)$$

where e is the electronic charge, Q is the quadrupolar moment of the bare nucleus of spin I . The factor R_{14} , which includes the electrostatic antishielding, is in the present frame of coordinates $Oxyz$ the value of the only nonzero components of the third rank tensor relating the electric field gradient to the electric field.³³⁻³⁵ The quantity $b_Q = eR_{14}Q[4\hbar\gamma I(2I-1)]^{-1}$ is the ratio of a magnetic to an electric field. It is calculated in Appendix A for different compounds and is given in Table I. The Hamiltonian H_Q can be rewritten as the sum of a static and of a modulated part

$$H_Q = [1 + h(t)]F_{0Q}(r) \cdot \sum (A_{Qk} + A_{Qk}^+) \quad (8)$$

where $F_{0Q}(r)$ is given by

$$F_{0Q}(r) = [1 - s(r)\Gamma_t] \cdot F_{Qoff}(r) = \hbar\gamma[1 - s(r)\Gamma_t] b_Q E_{off}(r) \quad (9)$$

and Γ_t is the fraction of the time during which the electron is present at the donor site. The function $h(t)$ describes temporal fluctuations due to the trapping and recombination of an electron at the localized site. This function has a time average equal to zero and varies randomly between $s(r)\Gamma_t[1 - s(r)\Gamma_t]^{-1}$ and $-s(r)(1 - \Gamma_t)[1 - s(r)\Gamma_t]^{-1}$. Its correlation function, as found in Appendix B, is given by

$$g(\tau) = \langle h(t)h(t - \tau) \rangle = \frac{\Gamma_t(1 - \Gamma_t)s(r)^2}{[1 - s(r)\Gamma_t]^2} \cdot e^{-\tau/\tau_{cQ}} \quad (10)$$

The latter result expresses the fact that the interaction is not modulated for $s = 0$ or $\Gamma_t = 0$ or $\Gamma_t = 1$. The correlation time τ_{cQ} for the quadrupolar interaction is the sum of two independent contributions

$$1/\tau_{cQ} = 1/\tau_r + 1/\tau_c \quad (11)$$

where τ_r is the recombination time of the electron at the donor and τ_c is the lifetime of the ionized donor due to capture of a free electron.

B Calculation of the nuclear relaxation time

Following a semi-classical treatment, the quadrupolar-induced evolution of the nuclear spin density matrix σ^* for the nuclear spin system, in the interaction representation and within the secular approximation, is given by³²

$$\left. \frac{d\sigma^*}{dt} \right|_Q = -\frac{i}{\hbar} [H_0, \sigma^*] - \frac{[F_{0Q}(r)]^2}{\hbar^2} \sum_k [A_{Qk}, [A_{Qk}^+, \sigma^* - \sigma_0]] J_Q(\omega_k) \quad (12)$$

where H_0 is the total static Hamiltonian and σ_0 is the steady-state value of σ^* . The spectral density function $J_Q(\omega_k)$, taken for ω_k defined by Eq. (6), is given by³⁹

$$J_Q(\omega_k) = \int_{-\infty}^{+\infty} e^{-i\omega_k\tau} g(\tau) d\tau \quad (13)$$

Under *the sole effect* of the quadrupolar spin-lattice relaxation, the evolution of the mean nuclear spin value $\langle \vec{I} \rangle$, calculated using $\langle A \rangle = Tr(\sigma A)$, is found to be nonexponential. Here, we further take into account the known existence of a nuclear spin temperature.⁴⁰ Using for the nuclear spin density matrix the expression valid in the high temperature limit,²⁹

$$\sigma \approx [1 - \beta(Z + H_I + H_Q + H_{SS})] / Tr(1) \quad (14)$$

where $\beta = 1/k_B T_n$, k_B is the Boltzmann constant and T_n is the temperature of the nuclear spin system, it is found that the nuclear mean spin lies along the direction of the magnetic field independently on the relative magnitudes of Zeeman and quadrupolar interactions.

Since the operator σ commutes with the static Hamiltonian, the density matrix in the interaction representation is $\sigma^* = \sigma$ and also the first term of Eq. (12) vanishes. An equation for evolution of the inverse nuclear spin temperature β is obtained, after multiplication of Eq. (12) by I_z , taking the trace, and using Eq. (14). Assuming that $\sigma \approx (1 - \beta Z) / Tr(1)$ [these large magnetic field conditions are defined more precisely in Sec. IIID], one obtains

$$\left. \frac{\partial \beta}{\partial t} \right|_Q = -\frac{1}{\hbar^2} [F_{0Q}(r)s(r)]^2 \frac{\Gamma_t(1-\Gamma_t)}{[1-s(r)\Gamma_t]^2} \left[\sum_k \frac{2K_k(I)\tau_{cQ}}{1+\omega_k^2\tau_{cQ}^2} \right] (\beta - \beta_L) \quad (15)$$

Here $\beta_L = 1/k_B T_L$, T_L being the temperature of the lattice. The numerical quantity $K_k(I)$, defined by

$$K_k(I) = Tr\{I_z [A_{Qk}, [A_{Qk}^+, I_z]]\} / Tr[I_z^2] \quad (16)$$

is calculated in Appendix C. Its value is as expected zero for $I = 1/2$ and is given by

$$K_1(I) = \frac{2}{5} [4I(I+1) - 3] \frac{E_{off\perp}^2}{E_{off}^2} \quad (17)$$

$$K_1(I) + K_2(I) = \frac{2}{5} [4I(I+1) - 3] \cdot \left[1 + 3 \frac{E_{off\parallel}^2}{E_{off}^2} \right] \quad (18)$$

where we recall that the parallel and perpendicular components of the electric field, defined with respect to the normal z to the surface, are equal to $E_{off} \cos\theta$ and $E_{off} \sin\theta$, respectively.

The quadrupolar relaxation rate is finally given by

$$\frac{1}{T_{1Q}} = \Gamma_t (1 - \Gamma_t) [\gamma b_Q (E_{off} - E_{on})]^2 \cdot \left[\frac{2K_1(I) \tau_{cQ}}{1 + \omega_1^2 \tau_{cQ}^2} + \frac{2K_2(I) \tau_{cQ}}{1 + \omega_2^2 \tau_{cQ}^2} \right] \quad (19)$$

Its value is proportional to the square of the amplitude of the modulated electric field. The quadrupolar-induced decrease of the nuclear magnetization is obtained by computing the ratio $f = T_{1Q}/T_{1H}$, where the relaxation time T_{1H} of the hyperfine interaction, is given by²⁸

$$\frac{1}{T_{1H}} = \Gamma_t [\gamma b_e^*(r)]^2 \frac{2\tau_{cH}}{1 + \omega_H^2 \tau_{cH}^2} \quad (20)$$

Here, $b_e^*(r)$ is the *instant* electronic hyperfine field acting on the nuclei. The time τ_{cH} is the correlation time of the hyperfine interaction. The energy $\hbar\omega_H$, corresponding to the flip-flop of an electronic and a nuclear spin, is given by

$$\hbar\omega_H \approx \hbar\gamma_e (B + B_n) \quad (21)$$

where B_n is the nuclear hyperfine field acting on the electrons. The latter energy, which depends on the *electronic* gyromagnetic ratio γ_e , is larger than $\hbar\omega_1$ and $\hbar\omega_2$ by about three orders of magnitude. Assuming finally that $\omega_H^2 \tau_{cH}^2$, $\omega_1^2 \tau_{cQ}^2$, and $\omega_2^2 \tau_{cQ}^2$ are small with respect to unity, which sets an upper limit to the magnetic field value, the quantity f is finally given by

$$f = \frac{T_{1Q}}{T_{1H}} \approx \frac{\tau_{cH}}{\tau_{cQ}} \cdot \frac{1}{(1 - \Gamma_t)} \left[\frac{b_e^*(r)}{b_Q (E_{off} - E_{on})} \right]^2 \cdot \left[\sum_k K_k(I) \right]^{-1} \quad (22)$$

Note that Eq. (19) and Eq. (22) have a quite general character: i) since the spatial dependence of the electric fields E_{off} and E_{on} , near shallow donor states, does not appear explicitly, these equations are valid for any localized electronic state; ii) if the magnetic field is not parallel to the z direction, the latter equations are still valid, provided the sum $\sum_k K_k(I)$ is modified. As seen from Eq. (A1), assuming that the magnetic field lies in the Oxz plane, at angle θ' with respect to z , one finds

$$K_1(I) + K_2(I) = \frac{2}{5} [4I(I+1) - 3] \left[1 + 3 \left(\frac{E_{off\ z} \cos \theta' - E_{off\ x} \sin \theta'}{E_{off}} \right)^2 \right] \quad (23)$$

which, for a given nuclear species, contains only an angular dependence on both the electric field direction and the magnetic field one. For nuclei near shallow donors, because of rotational symmetry, the value of the nuclear field, obtained after averaging over θ , should weakly depend on θ' . The latter anisotropy should be most observable for systems where one of the components of the electric field can be dominant, such as quantum dots.^{41,42}

Coming back to the simpler case of nuclei near a donor and of B along the z direction, one has

$$b_o E_{off}(r) = b_o E_{off}(a_o^*) \cdot (a_o^*/r)^2 \quad (24)$$

$$b_e^*(r) = b_e^*(a_o^*) e^{-2(r/a_o^*-1)} \quad (25)$$

Using Eq. (2), Eq. (17), and Eq. (18), it is possible to separate the quantity f into the product of a radial dependence $\varphi(r)$, of an angular one, and of a numerical coefficient f_0 which is a measure of the relative strengths of hyperfine to quadrupolar relaxations:

$$f = f(r, \theta) \approx \frac{f_0 \varphi(r)}{1 + 3 \cos^2 \theta} \quad (26)$$

$$\varphi(r) = \frac{e^{-4(r/a_o^*-1)} \left(\frac{r}{a_o^*} \right)^4}{s(r)^2} \quad (27)$$

$$f_0 = \frac{5}{2} [4I(I+1) - 3]^{-1} (1 - \Gamma_t)^{-1} \frac{\tau_{cH}}{\tau_{cQ}} \left(\frac{b_e^*(a_0^*)}{b_e E_{off}(a_0^*)} \right)^2 \quad (28)$$

The implications of the latter equations are discussed in the following section.

III Discussion

A Effect of the donor rate of occupation.

A key parameter for the value of f_0 is the rate of occupation of the donors Γ_t by photoelectrons, which depends on the light excitation power. Indeed:

a) The correlation times τ_{cH} , and τ_{cQ} depend on the free electron density n_f . The time τ_{cQ} can be written using Eq. (11)

$$\frac{1}{\tau_{cQ}} = \frac{1}{\tau_r} + \sigma_c v n_f \quad (29)$$

where v is the velocity of free electrons and σ_c is the cross section for their capture at donors.

The correlation time τ_{cH} of the hyperfine interaction is given by

$$\frac{1}{\tau_{cH}} = \frac{1}{2\tau_r} + \frac{1}{T_1} + \frac{1}{\tau_{ex}} \approx \sigma_e v n_f \quad (30)$$

as obtained in Appendix B, assuming that the electronic polarization is weak with respect to unity. Here T_1 is the electronic spin–lattice relaxation time and τ_{ex} is the characteristic time for spin exchange between trapped and free electrons. In GaAs, it has been found that the latter process is dominant by several orders of magnitude, so that τ_{cH} has a simple approximate expression, also given in Eq. (30), where σ_e is the spin exchange cross section.²¹

b) The rate Γ_t of donor occupation is obtained by writing rate equations for the population of electrons trapped at donors, of concentration N_D . In steady-state, the rate of

recombination for electrons trapped at shallow donors $[\Gamma_t N_D \tau_r^{-1}]$ is equal to that of trapping for free electrons $[\sigma_c (1 - \Gamma_t) N_D v n_f]$. Thus Γ_t is given by

$$\Gamma_t = \frac{\sigma_c \tau_r v n_f}{1 + \sigma_c \tau_r v n_f}. \quad (31)$$

Using Eq. (29), Eq. (30) and Eq. (31), f_0 is given by

$$f_0 = \frac{5}{2} \frac{\sigma_c}{\sigma_e} [4I(I+1) - 3]^{-1} \left(\frac{b_e^*(a_0^*)}{b_o E_{off}(a_0^*)} \right)^2 \frac{1}{\Gamma_t (1 - \Gamma_t)} = \frac{f_{00}}{\Gamma_t (1 - \Gamma_t)} \quad (32)$$

Eq. (32) has a simple form in which the quantity f_{00} , which is a measure of the maximum magnitude of the quadrupolar-induced loss of nuclear magnetization, is independent of experimental conditions such as excitation power. The latter dependence is concentrated in the rate Γ_t of occupation of the donors. According to Eq. (32), the quadrupolar-induced loss of nuclear polarization occurs when the donors are *partially* occupied, which can be easily characterized from the power dependence of the donor luminescence. For a density of conduction electrons much smaller than $(\sigma_c \tau_r v)^{-1}$, one has $\Gamma_t \ll 1$ and the quadrupolar effects are small since the correlation time τ_{cH} is large. Conversely, if $\Gamma_t = 1$, the quadrupolar interaction is not modulated and cannot relax the nuclear spins.

B Order of magnitude estimates

For As⁷⁵ in GaAs, the efficiency of the quadrupolar relaxation process comes from the fact that the spin exchange cross section $[\sigma_e \sim 9 \times 10^{-16} \text{ m}^2]$ ²¹ is three orders of magnitude larger than the one for electron capture at donors $[\sigma_c = 5.1 \times 10^{-19} \text{ m}^2]$.⁴³ Using Table I and Ref. (10), we obtain $b_e^*(a_0^*) = 1.5 \text{ mT} \approx 11 b_o E_{off}(a_0^*)$ and we find $f_{00} \sim 1 \times 10^{-2}$, and $f_0 \sim 4 \times 10^{-2}$ for $\Gamma_t = 1/2$. As found from Eq. (26), $f(a_0^*)$ is equal to 0.4 at $\theta = 90^\circ$ and 0.1 at $\theta = 0^\circ$, so that the nuclei at the Bohr radius are depolarized by the quadrupolar relaxation.

Using a velocity equal to the thermal velocity at 10K and τ_r of the order of 1 ns,⁴⁴ we find a critical photoelectron density $(\sigma_c \tau_r \nu)^{-1}$ at which $\Gamma_i=1/2$ equal to $(\sigma_c \tau_r \nu)^{-1}=10^{22} \text{ m}^{-3}$. The corresponding excitation power density is estimated using a resolution of the standard diffusion equation⁴⁵ which, assuming a small surface recombination velocity, gives a density of photons per second $g = n_f L_e / \tau_f$. Taking a diffusion length for minority carriers $L_e=5\mu\text{m}$,⁴⁶ and a value of the recombination time of free electrons $\tau_f=20 \text{ nsec}$,⁴⁴ we estimate that the power density should be of the order of $3 \times 10^2 \text{ W/cm}^2$, which is a realistic value.

Nuclei such as In^{115} in InP and Sb^{121} in GaSb are believed to exhibit stronger quadrupolar effects because of their larger spin values (9/2 for In^{115} and 5/2 for Sb^{121}). However, as seen in Table I, the quantity b_Q is smaller than for As^{75} in GaAs. Using Table I and Eq. (33) and assuming that both σ_c and σ_e scale like the Bohr radius, so that their ratio is independent on material, we estimate that f_{00} is equal to 4.4×10^{-2} and 4.8×10^{-2} for In^{115} in InP and Sb^{121} in GaSb respectively. This implies that the latter materials should also exhibit nuclear polarization losses of quadrupolar origin, although smaller than for GaAs.

Coming to a comparison with experimental results, among the works which have estimated the leakage factor f ,^{22, 23, 29} none of them has discussed the donor rate of occupation. Although it has been observed in GaAs that nuclear effects decrease when the excitation power density is increased into the range defined above,⁴⁷ it is concluded that further studies, in particular as a function of light excitation power, are necessary in order to experimentally verify the importance of the light-induced quadrupolar relaxation. Such studies are beyond the scope of the present paper and will be published elsewhere for the case of quantum dots.³⁶

C Radial and angular dependences of the nuclear polarization: quadrupolar diffusion radius

The nuclear polarization $p(r, \theta)$, in reduced units, is given by

$$p(r, \theta) = \frac{T_{1Q}}{T_{1Q} + T_{1H}} = \frac{f(r, \theta)}{[1 + f(r, \theta)]} \quad (33)$$

where $f(r, \theta)$ is given by Eq. (26). Shown in Fig. 1 are the radial dependences of $p(r, 0)$, $p(r, 90)$ using $f_0 \sim 10^{-2}$. Close to the donor position, one has $p(r, \theta) = 1$, as the quadrupolar relaxation is inefficient because $s(r) \approx \frac{4}{3} \left(r/a_0^* \right)^3$ so that the electric field is not modulated. As a function of distance, although the quadrupolar rate first increases and then decreases, f exhibits a monotonic, decreasing behavior. The nuclei are depolarized above a distance to the donor corresponding to $f = 1$. As seen in Fig. 1, this distance is smaller in the direction z of the magnetic field ($0.25a_0^*$) than in the perpendicular directions ($0.45a_0^*$).

For calculation of the nuclear field two approximations will be made. First, we shall use for simplicity the *angular* average of the nuclear polarization, defined as $\langle p(r) \rangle = \int \sin \theta p(r, \theta) d\theta d\varphi / \int \sin \theta d\theta d\varphi$. As found using Eq. (26) and Eq. (27), this quantity is given by

$$\langle p(r) \rangle = \frac{f_0 \varphi(r)}{\sqrt{3[1 + f_0 \varphi(r)]}} \operatorname{Arctg} \left[\frac{\sqrt{3}}{\sqrt{1 + f_0 \varphi(r)}} \right] \quad (34)$$

for which the radial dependence, also shown in Fig. 1, is intermediate between those of $p(r, 0)$ and $p(r, 90)$. The second approximation consists in replacing $\langle p(r) \rangle$ by a step function at $r = \rho_Q$ such that $\langle p(\rho_Q) \rangle = 1/2$. Thus, the nuclear hyperfine field, defined by

$$B_n = B_{n0} a_0^{*-3} \int_0^\infty 4r^2 e^{-2r/a_0^*} \langle p(r) \rangle dr,^{29}$$
 is given by

$$B_n \approx B_{n0} s(\rho_Q) \quad (35)$$

where B_{n0} is the nuclear field value for a homogeneous nuclear polarization, and $s(r)$ is defined in Eq. (3). The latter approximation implies that the quadrupolar relaxation is inefficient for distances smaller than ρ_Q and dominant for larger distances ($f=0$). Such

approximation is usual in analyses of nuclear polarizations near shallow donors,¹⁶⁻¹⁸ and results in defining a sphere around the donor inside which the nuclear polarization is not affected by the quadrupolar relaxation. The radius of this sphere, which will be called the quadrupolar radius, replaces the usual diffusion radius for the estimate of the nuclear hyperfine field.

Shown in Fig. 2 are the variations of ρ_Q and of $s(\rho_Q)$, as a function of f_0 . For $f_0 = 10^{-2}$, one finds as shown in Fig. 1 $\rho_Q \sim 0.35a_0^*$, which is smaller than the usual diffusion radius, $\rho_D \sim 1.4a_0^*$, beyond which, due to spin diffusion, a homogeneous nuclear magnetization builds up slowly.²⁸ Thus, for the latter value of f_0 , the nuclear field experienced by the electron trapped at the donor is smaller by about one order of magnitude than its value $s(\rho_D) \approx 0.5$ due to the sole spin diffusion. As seen from the latter figure, the quadrupolar-induced decrease of the nuclear field should occur for f_0 smaller than about 10^{-1} . It is found that this condition is fulfilled if the power density lies within about one order of magnitude on each side of the critical photoelectron density $(\sigma_c \tau_r \nu)^{-1}$ defined in subsection III.A.

Note finally that since the usual diffusion radius ρ_D depends on a balance between spin-lattice relaxation and diffusion, ρ_D should itself be decreased by the presence of an additional relaxation mechanism. Using Ref. (21) and the above estimates, we calculate a modified diffusion radius ρ_{DQ} value close to the Bohr radius value. Since $\rho_{DQ} > \rho_Q$, the nuclei at ρ_{DQ} are weakly-polarized, so that the *bulk* nuclei, polarized by diffusion from the latter nuclei, should also have a reduced polarization.

D Magnetic field effects

With the above values of the correlation times, the zero magnetic field expression of the quadrupolar-induced decrease of nuclear magnetization [Eq. (22)] is valid up to a very large

magnetic field. On the other hand, at very low magnetic field, Eq. (22) is not valid, since the Zeeman term of the Hamiltonian no longer dominates the other terms. The lower magnetic field limit is obtained by expressing the heat capacities of the various reservoirs using the following relation²⁹

$$\frac{\langle Z \rangle}{B^2} = \frac{\langle H_{ss} \rangle + \langle H_Q \rangle}{B_L^2 + B_Q^2} = -\frac{1}{k_B T_n} \frac{I(I+1)}{3} (\gamma \hbar)^2 \quad (36)$$

where the electronic field acting on the nuclear spins has been neglected. Here B_L is the local field and the local field of quadrupolar origin B_Q , equal to zero for $I = 1/2$, is given by

$$B_Q^2 = \frac{3 \text{Tr} \langle H_Q^2 \rangle}{I(I+1)(2I+1)(\gamma \hbar)^2} = \frac{4}{5} (b_Q E_{off})^2 (1 - s\Gamma_t)^2 [4I(I+1) - 3] \quad (37)$$

We conclude that Eq. (22) is valid provided

$$B^2 \gg B_L^2 + B_Q^2 \quad (38)$$

Thus the *effective* local field is larger than the spin-spin local field. For a magnetic field along the z direction, assuming for simplicity $\Gamma_t = 0$ and taking $r \approx 0.5a_0^*$, we calculate $B_Q \sim 1.6$ mT which is about one order of magnitude larger than B_L .²⁹

V Conclusion

We now summarize the main results of the present work:

a) It is found that the evolution of the nuclear spin temperature caused by modulation of the electric field induced by optical excitation of the semiconductor is exponential. The corresponding time, within numerical factors, depends on the product of the square of the modulation amplitude and of the correlation time of the modulation. Comparison of the latter

time with that of the hyperfine contact interaction gives the expression for the nuclear polarization under the combined effects of quadrupolar and hyperfine relaxations.

b) Near shallow donors in semiconductors, the angular-averaged effect of the quadrupolar relaxation is to replace the diffusion radius ρ_D up to which the nuclei are spin-polarized by a novel, smaller, radius called here the *quadrupolar radius* ρ_Q .

c) The quadrupolar-induced decrease of the quadrupolar radius and of the nuclear field occurs in conditions of light excitation corresponding to partial donor occupation by photoelectrons. For GaAs, we estimate $\rho_Q \sim 0.45 a_0^* \sim 0.3 \rho_D$. This should induce a decrease of the nuclear field by as much as one order of magnitude and by slightly smaller factors for InP and GaSb.

Appendix A : Form and magnitude of the quadrupolar Hamiltonian

The quadrupolar Hamiltonian H_Q of a given nucleus at position \vec{r} is related to the components of the electric field gradient by^{37,38}

$$H_Q(\vec{r}) = \frac{eQ}{4I(2I-1)} \left\{ \begin{array}{l} V_{ZZ}(\vec{r})[3I_z^2 - I(I+1)] \\ + V_{X'Z}(\vec{r})[I_z(I_+ + I_-) + (I_+ + I_-)I_z] - iV_{Y'Z}(\vec{r})[I_z(I_+ - I_-) + (I_+ - I_-)I_z] \\ + \frac{1}{2}[V_{X'X'}(\vec{r}) - V_{Y'Y'}(\vec{r})][I_+^2 + I_-^2] - iV_{X'Y'}(\vec{r})[I_+^2 - I_-^2] \end{array} \right\} \quad (A1)$$

where the quantization axis Z' is the magnetic field direction, the spin operators I_{\pm} are equal to $I_{X'} \pm iI_{Y'}$ and

$$V_{ij}(\vec{r}) = \frac{\partial^2 E(\vec{r})}{\partial X'_i \partial X'_j} \quad (A2)$$

and X'_i stands for X' , Y' , or Z' . These directions are distinct from the xyz directions of the cubic crystal lattice, z being also the normal to the sample surface. The components of the electric field gradient tensor in the $X'Y'Z'$ frame are obtained by using elementary rules for tensor transformation and are given by³⁵

$$\begin{pmatrix} V_{X'X'} \\ V_{Y'Y'} \\ V_{Z'Z'} \\ V_{Y'Z'} \\ V_{X'Z'} \\ V_{X'Y'} \end{pmatrix} = R_{14} \begin{pmatrix} -\sin 2\theta' \sin \varphi' & -\sin 2\theta' \cos \varphi' & \cos^2 \theta' \sin 2\varphi' \\ 0 & 0 & -\sin 2\varphi' \\ \sin 2\theta' \sin \varphi' & \sin 2\theta' \cos \varphi' & \sin^2 \theta' \sin 2\varphi' \\ \cos \theta' \cos \varphi' & -\cos \theta' \sin \varphi' & \sin \theta' \cos 2\varphi' \\ \cos 2\theta' \sin \varphi' & \cos 2\theta' \cos \varphi' & \frac{1}{2} \sin 2\theta' \sin 2\varphi' \\ -\sin \theta' \cos \varphi' & \sin \theta' \sin \varphi' & \cos \theta' \cos 2\varphi' \end{pmatrix} \begin{pmatrix} E_x \\ E_y \\ E_z \end{pmatrix} \quad (A3)$$

where θ' and φ' are the angles between z and Z' and between x and the zZ' plane respectively. Here, R_{14} is the sum of an ionic contribution, (which depends on the ionicity of the solid, on $\varepsilon^2 - n$, where n is the infra-red optical index, and on the antishielding factor) and of the covalent contribution (which further depends on the bandgap value).³³

The expression of the quadrupolar Hamiltonian is then obtained from Eq. (A1) and (A3). For an arbitrary orientation of the magnetic field, this expression is intricate and depends both on θ' and φ' . This expression is simpler if B lies in the Oxz plane ($\varphi'=0$) in which case Eq. (23) is obtained. If the magnetic field B direction coincides with a [100] crystal axis z , ($\theta'=\varphi'=0$) the only nonzero components of V_{ij} in the xyz frame are

$$\begin{aligned} V_{xy} &= R_{14} E(\vec{r}) \cos \theta \\ V_{yz} &= R_{14} E(\vec{r}) \sin \theta \cos \varphi \\ V_{zx} &= R_{14} E(\vec{r}) \sin \theta \sin \varphi \end{aligned} \quad (\text{A4})$$

where we recall that θ and φ are the angles between the direction Z of the electric field and z and between x and the zZ plane, respectively. Eq. (4) is readily obtained.

In order to estimate b_Q , it is necessary to determine R_{14} . One of the most accurate determinations was performed for GaAs, where the effect of application of an electric field along the [111] direction on the quadrupolar splitting of the NMR line was studied.³³ The obtained R_{14} value was found to coincide with theoretical estimates. For GaAs, InAs and GaSb, independent estimates of R_{14} were obtained using the broadening of the nuclear acoustic resonance.³⁴ For GaAs, they differ from the latter value by about a factor of 3-4. As a result, for a nucleus α of InAs or GaSb, we have chosen to determine R_{14}^α according to the following scaling involving Ref. (33) and Ref. (34)

$$R_{14}^\alpha = R_{14}^\alpha(\text{REF.34}) \cdot \frac{R_{14}^{\text{As}}(\text{REF.33})}{R_{14}^{\text{As}}(\text{REF.34})} \quad (\text{A5})$$

For In^{115} in InP no estimate of R_{14} has to our knowledge been published. However, R_{14} of In^{115} in InP should not differ from that of In^{115} in InAs by more than a factor of 50% since the ionicities of InAs and InP are identical and since the effect of bandgap should be similar to the ratio of the R_{14} values of As^{75} between GaAs and InAs. The final results are shown in Table I.

Appendix B: Correlation functions of the quadrupolar and hyperfine interactions

The modulation of the quadrupolar interaction is described by the function $h(t)$, given by Eq. (9). This function is of zero average and takes two discrete values h_α (where $\alpha = 1,2$) given respectively by $h_1 = s\Gamma_t(1-s\Gamma_t)^{-1}$ or $h_2 = -s(1-\Gamma_t)(1-s\Gamma_t)^{-1}$, with respective probabilities $w_1 = \Gamma_t$ and $w_2 = 1 - \Gamma_t$. The correlation function is written under the form

$$g_Q(\tau) = \langle h(t)h(t-\tau) \rangle = \sum_\alpha h_\alpha w_\alpha \sum_\beta h_\beta P_{\alpha\beta}(\tau) \quad (\text{B1})$$

where $P_{\alpha\beta}(\tau)$ is the cardinal probability that $h = h_\beta$ at time τ , under the condition that $h = h_\alpha$ at time $t = 0$.

Assuming that the fluctuation process is Markovian and stationary, the quantity $P_{\alpha\beta}(\tau)$ is given by⁴⁸

$$\frac{dP_{\alpha\beta}}{dt} = \sum_\gamma \Pi(\gamma, \beta) P_{\alpha\beta}(t) \quad (\text{B2})$$

where $\Pi(\gamma, \beta)$ is a numerical factor, equal for $\gamma \neq \beta$ to the probability per unit time that $h(t)$ goes from the value h_γ to the value h_β . The quantity $-\Pi(\beta, \beta)$ is the probability that $h(t)$ goes from f_β to the other value. One has $\Pi(1,2) = \tau_1^{-1}$, $\Pi(2,1) = \tau_2^{-1}$, $\Pi(2,2) = -\tau_1^{-1}$, $\Pi(1,1) = -\tau_2^{-1}$, where τ_α is the lifetime of state α . Using the latter values, resolution of Eq. (B2) yields

$$\begin{aligned} P_{11} &= (1-\Gamma_t) + \Gamma_t \exp[-t(\tau_1^{-1} + \tau_2^{-1})] \\ P_{21} &= (1-\Gamma_t) - (1-\Gamma_t) \exp[-t(\tau_1^{-1} + \tau_2^{-1})] \\ P_{12} &= \Gamma_t - \Gamma_t \exp[-t(\tau_1^{-1} + \tau_2^{-1})] \\ P_{22} &= \Gamma_t + (1-\Gamma_t) \exp[-t(\tau_1^{-1} + \tau_2^{-1})] \end{aligned} \quad (\text{B3})$$

The result of Eq. (10) is obtained after replacing $P_{\alpha\beta}$ by their latter values in Eq. (B1).

The same procedure can be applied to calculate the correlation function for the hyperfine interaction. Here three states, labelled +1, -1, or 0 are considered, depending on the absence or presence of an electron of a spin equal to +1/2 or -1/2. In addition with the recombination time τ_r , the correlation time also depends on the spin-lattice relaxation time T_1 and of the characteristic time τ_{ex} due to possible spin-exchange processes with delocalized electrons. The final expression for the correlation function, valid in the limit of small electronic polarizations (i. e. $\tau_{ex}^{-1} + T_1^{-1} \gg \tau_r^{-1}$), is

$$g_H(\tau) = \Gamma_t \cdot e^{-\tau/\tau_{ch}} \quad (\text{B4})$$

where τ_{ch} is given by Eq. (30). Eq. (B4) expresses the fact that, unlike for the quadrupolar coupling, the hyperfine relaxation is inefficient in the only case where the probability Γ_t of occupation of the localized state is zero.

Appendix C : Expression of $K_k(I)$ defined by Eq. (16)

Applying the relations $\text{Tr}(ABC) = \text{Tr}(BCA)$ and $\text{Tr}\{A [B, [C, D]]\} = \text{Tr}\{[A, B][C, D]\}$

where A, B, C and D are spin operators, one obtains

$$\text{Tr}\left\{I_z [A_{Q,k}, [A_{Q,k}^+, I_z]]\right\} = \text{Tr}\left\{[I_z, A_{Q,k}] [A_{Q,k}^+, I_z]\right\} \quad (\text{C1})$$

One finds

$$\text{Tr}\left\{I_z [A_{Q,2}, [A_{Q,2}^+, I_z]]\right\} = \sin^2 \theta \frac{\text{Tr}\left[(I_+ I_-)^2 + 2I_- I_+ I_z\right]}{\text{Tr}\left[I_z^2\right]} \quad (\text{C2})$$

$$\text{Tr}\left\{I_z [A_{Q,3}, [A_{Q,3}^+, I_z]]\right\} = 4 \cos^2 \theta \frac{\text{Tr}\left[(I_+ I_-)^2 + 2I_- I_+ I_z\right]}{\text{Tr}\left[I_z^2\right]} \quad (\text{C3})$$

The calculation proceeds using the following relations, where m is the quantum number of I_z

$$I_{\pm} I_{\mp} |m\rangle = [I(I+1) - m(m \mp 1)] |m\rangle \quad (\text{C4})$$

$$\text{Tr}(I_z^2) = \frac{1}{3} I(I+1)(2I+1) \quad (\text{C5})$$

$$\text{Tr}(I_z^4) = \frac{1}{5} I(I+1)(2I+1) \left[I(I+1) - \frac{1}{3} \right] \quad (\text{C6})$$

and gives the results shown in Eq. (17) and Eq. (18).

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quadrupolar interactions, there is little doubt that there exists a spin temperature among the nuclear spin system.

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Figure captions

Fig. 1

Dependence of the normalized nuclear magnetization, defined by Eq. (33), as a function of distance. The relative magnitude f_0 of hyperfine and quadrupolar relaxations, given by Eq. (28), is taken as equal to 10^{-2} . The distance at which the magnetization is equal to 0.5 is of $0.25 a_0^*$ in the direction of the magnetic field (a) and $0.45 a_0^*$ in the perpendicular direction (b) and $\rho_Q = 0.35 a_0^*$ after angular averaging.(c)

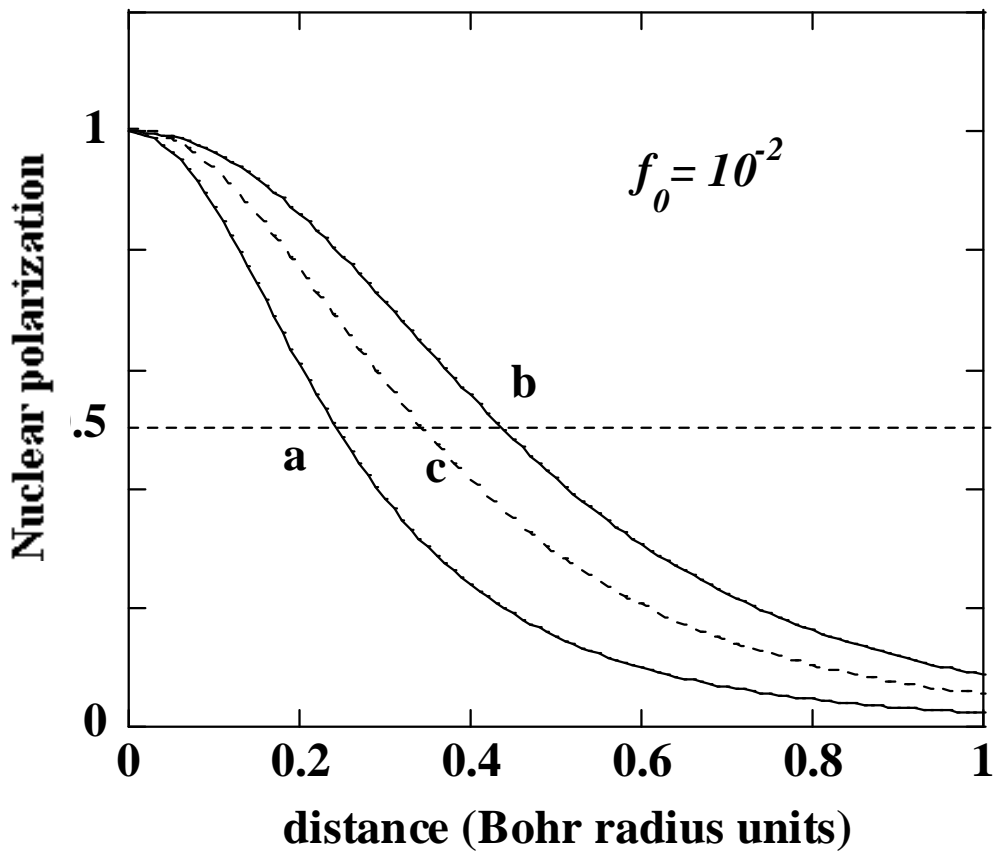


Fig. 2 : Dependence of the quadrupolar radius ρ_Q and on the nuclear field on the relative magnitude f_0 of hyperfine and quadrupolar relaxations. If no light-induced quadrupolar relaxation is present, the quadrupolar radius is replaced by the usual diffusion radius, ρ_D , of the order of the Bohr radius. For $f_0 = 10^{-2}$, the quadrupolar radius is $0.35a_0^*$, and the nuclear field is further decreased by about one order of magnitude.

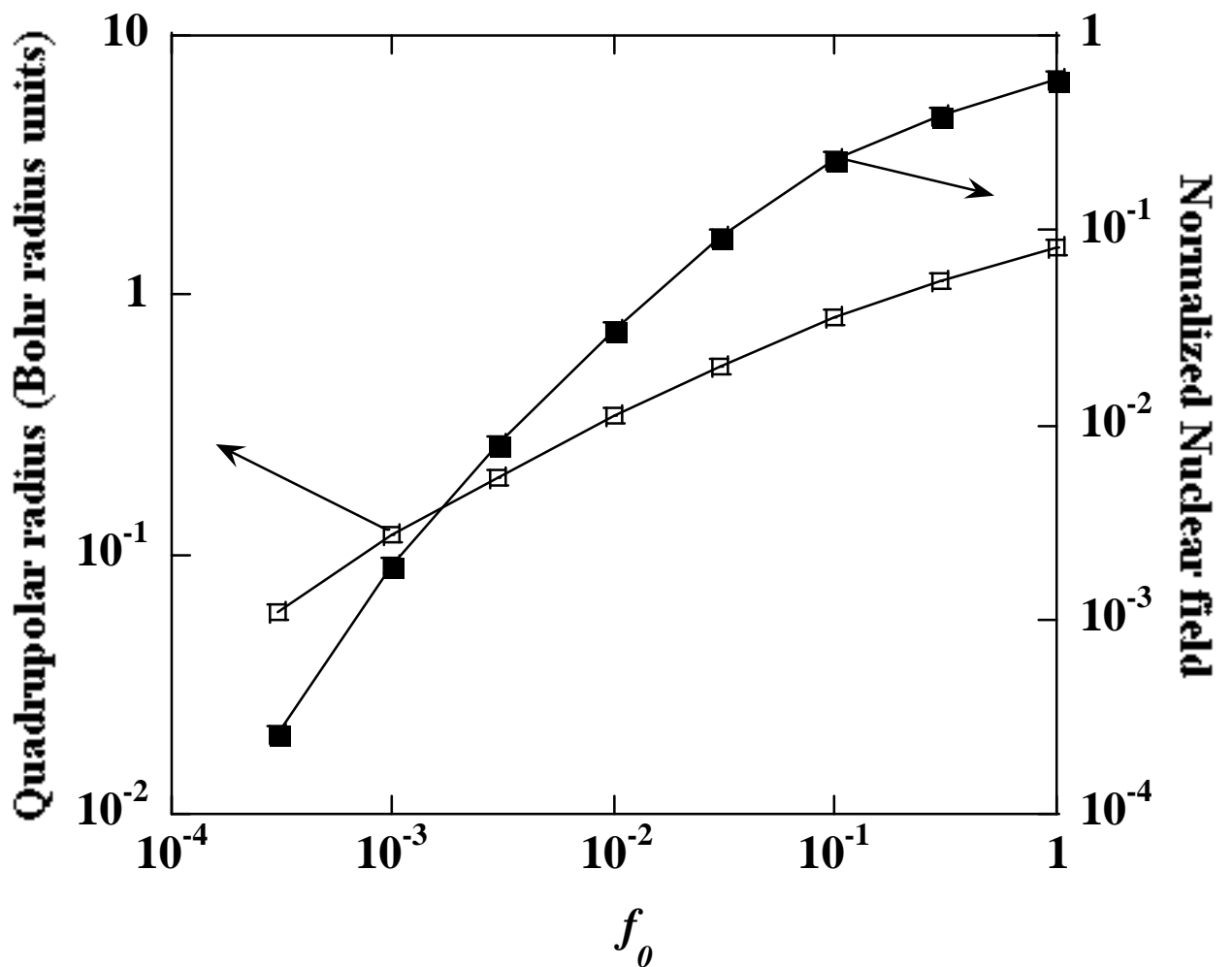


Table I : Estimate of b_Q

The quantity b_Q , which has the dimension of the ratio of a magnetic field to an electric field, is given by Eq. (7) and characterizes the strength of the quadrupolar relaxation. This quantity estimated in Appendix A, is given below for several nucleus/semiconductor matrix combinations (the isotopic specie under consideration is indicated in bold).

Nucleus	R_{14} (10^{12} m^{-1})	b_Q (10^{-10} Tm/V)
GaAs ⁷⁵	1.5	1.3
Ga ⁶⁹ As	1.05	0.75
Ga ⁷¹ As	0.9	0.60
In ¹¹⁵ As	2.1	0.32
In As ⁷⁵	0.9	0.78
Ga ⁶⁹ Sb	0.26	0.19
GaSb ¹²¹	0.9	0.56
In ¹¹⁵ P	~ 2	~ 0.30